查询MCR218-10FP供应商

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MCR218-6FP, MCR218-10FP

Preferred Device

Silicon Controlled Rectifiers

Reverse Blocking Thyristors

Designed primarily for half-wave ac control applications, such as motor controls, heating controls and power supply crowbar circuits.

- Glass Passivated Junctions with Center Gate Fire for Greater Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Constructed for Low Thermal Resistance, High Heat Dissipation and Durability
- Blocking Voltage to 800 Volts
- 80 A Surge Current Capability
- Insulated Package Simplifies Mounting
- 🔊 Indicates UL Registered File #E69369
- Device Marking: Logo, Device Type, e.g., MCR218-6, Date Code

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage(1) (TJ = -40 to +125°C, Sine Wave 50 to 60 Hz, Gate Open)	V _{DRM,} V _{RRM}		Volts
MCR218–6FP MCR218–10FP		400 800	
On-State RMS Current (T _C = +70°C) ⁽²⁾ (180° Conduction Angles)	IT(RMS)	8.0	Amps
Peak Nonrepetitive Surge Current (1/2 Cycle, Sine Wave 60 Hz, T _J = 125°C)	ITSM	100	Amps
Circuit Fusing (t = 8.3 ms)	l ² t	26	A ² s
Forward Peak Gate Power ($T_C = +70^{\circ}C$, Pulse Width $\leq 1.0 \mu$ s)	PGM	5.0	Watts
Forward Average Gate Power ($T_C = +70^{\circ}C, t = 8.3 \text{ ms}$)	PG(AV)	0.5	Watt
Forward Peak Gate Current $(T_C = +70^{\circ}C, Pulse Width \le 1.0 \mu s)$	I _{GM}	2.0	Amps
RMS Isolation Voltage (T _A = 25°C, Relative Humidity ≤ 20%) (ℜ)	V _(ISO)	1500	Volts
Operating Junction Temperature	TJ	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

(1) VDRM and VRRM for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

(2) The case temperature reference point for all T_C measurements is a point on the center lead of the package as close as possible to the plastic body.





ON Semiconductor

http://onsemi.com

ISOLATED SCRs (9\) 8 AMPERES RMS 400 thru 800 VOLTS





ISOLATED TO-220 Full Pack CASE 221C STYLE 2

PIN ASSIGNMENT		
1	Cathode	
2	Anode	
3	Gate	

ORDERING INFORMATION

Device	Package	Shipping
MCR218-6FP	ISOLATED TO220FP	500/Box
MCR218-10FP	ISOLATED TO220FP	500/Box

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	R _{θJC}	2	°C/W
Thermal Resistance, Case to Sink	$R_{\theta CS}$	2.2 (typ)	°C/W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	60	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	тլ	260	°C

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
$\begin{array}{l} \mbox{Peak Repetitive Forward or Reverse Blocking Current} \\ (V_D = Rated V_{DRM}, Gate Open) & T_J = 25^\circ C \\ T_J = 125^\circ C \end{array}$	IDRM, IRRM			10 2	μA mA
ON CHARACTERISTICS					
Peak Forward On–State Voltage ⁽¹⁾ (I _{TM} = 16 A Peak)	V _{TM}	-	1	1.8	Volts
Gate Trigger Current (Continuous dc) (V _{AK} = 12 Vdc, R _L = 100 Ohms)	I _{GT}	-	10	25	mA
Gate Trigger Voltage (Continuous dc) (V _{AK} = 12 Vdc, R _L = 100 Ohms)	V _{GT}	-	-	1.5	Volts
Gate Non-Trigger Voltage (V _{AK} = 12 Vdc, R _L = 100 Ohms, T _J = 125°C)	V _{GD}	0.2	-	-	Volts
Holding Current (V _{AK} = 12 Vdc, Initiating Current = 200 mA, Gate Open)	Ч	-	16	30	mA
Turn-On Time (I _{TM} = 8 A, I _{GT} = 40 mAdc)	tgt	—	1.5	-	μs
Turn-Off Time (V _D = Rated V _{DRM} , I_{TM} = 8 A, I_R = 8 A) T_J = 25°C T_J = 125°C	tq		15 35		μs

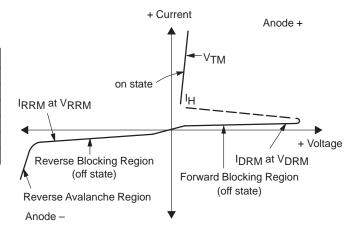
DYNAMIC CHARACTERISTICS

Critical Rate-of-Rise of Off-State Voltage (Gate Open, V _D = Rated V _{DRM} , Exponential Waveform)	dv/dt	—	100	—	V/µs
(Gale Open, VD - Raide VDRM, Experiential Wavelenn)					

(1) Pulse Test: Pulse Width = 1 ms, Duty Cycle $\leq 2\%$.

Voltage Current Characteristic of SCR

Symbol	Parameter
VDRM	Peak Repetitive Off State Forward Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Off State Reverse Voltage
IRRM	Peak Reverse Blocking Current
VTM	Peak on State Voltage
ΙΗ	Holding Current



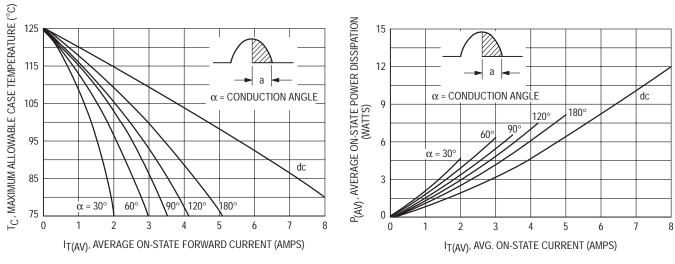


Figure 1. Current Derating

Figure 2. On-State Power Dissipation

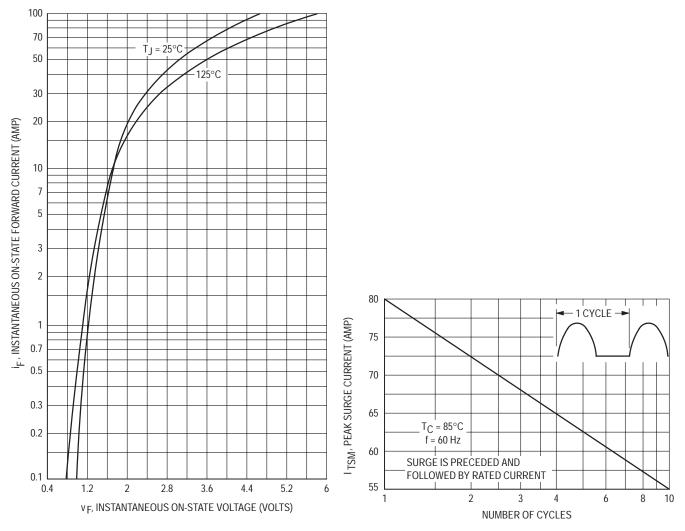


Figure 3. Maximum On-State Characteristics

Figure 4. Maximum Non-Repetitive Surge Current

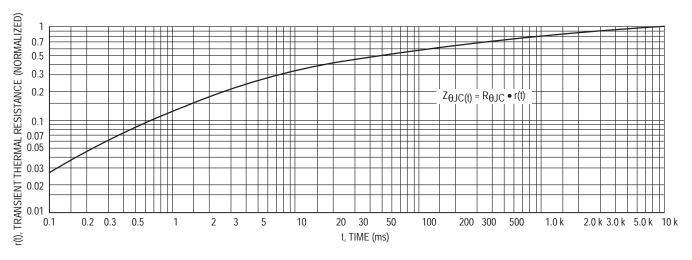
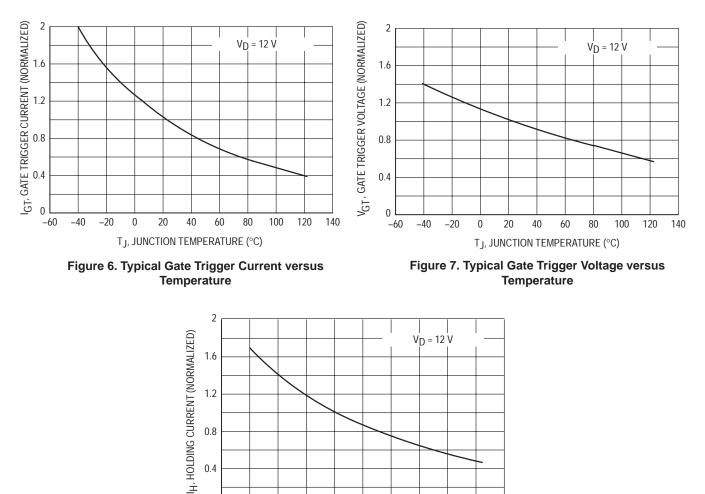


Figure 5. Thermal Response



TJ, JUNCTION TEMPERATURE (°C)

20

0.8

0.4

0 -60

-40

-20

0

Figure 8. Typical Holding Current versus Temperature

40

60

80

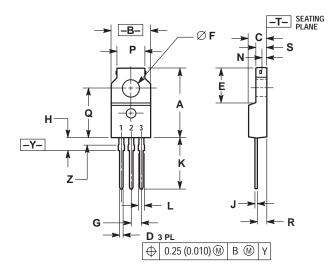
100

120

140

PACKAGE DIMENSIONS

ISOLATED TO-220 Full Pack CASE 221C-02 **ISSUE C**



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. LEAD DIMENSIONS UNCONTROLLED WITHIN DIMENSION Z.

	INCHES		INCHES MILLIMET		IETERS
DIM	MIN	MAX	MIN	MAX	
Α	0.680	0.700	17.28	17.78	
В	0.388	0.408	9.86	10.36	
С	0.175	0.195	4.45	4.95	
D	0.025	0.040	0.64	1.01	
Е	0.340	0.355	8.64	9.01	
F	0.140	0.150	3.56	3.81	
G	0.100 BSC		2.54 BSC		
Н	0.110	0.155	2.80 3.9		
J	0.018	0.028	0.46	0.71	
К	0.500	0.550	12.70	13.97	
L	0.045	0.070	1.15	1.77	
Ν	0.049		1.25		
Р	0.270	0.290	6.86	7.36	
Q	0.480	0.500	12.20	12.70	
R	0.090	0.120	2.29	3.04	
S	0.105	0.115	2.67	2.92	
Ζ	0.070	0.090	1.78	2.28	

STYLE 2: PIN 1. CATHODE 2. ANODE 3. GATE

<u>Notes</u>

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